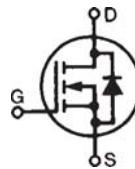


# Linear™ Power MOSFET w/ Extended FBSOA

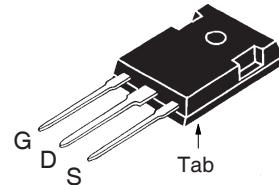
## IXTH24N50L



N-Channel Enhancement Mode  
Avalanche Rated

**V<sub>DSS</sub>** = 500V  
**I<sub>D25</sub>** = 24A  
**R<sub>DS(on)</sub>** ≤ 300mΩ

TO-247



G = Gate      D = Drain  
S = Source      Tab = Drain

Symbol	Test Conditions	Maximum Ratings	
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 150°C	500	V
V <sub>DGR</sub>	T <sub>J</sub> = 25°C to 150°C, R <sub>GS</sub> = 1MΩ	500	V
V <sub>GSS</sub>	Continuous	± 30	V
V <sub>GSM</sub>	Transient	± 40	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	24	A
I <sub>DM</sub>	T <sub>C</sub> = 25°C, Pulse Width Limited by T <sub>JM</sub>	50	A
I <sub>A</sub>	T <sub>C</sub> = 25°C	12	A
E <sub>AS</sub>	T <sub>C</sub> = 25°C	1.5	J
P <sub>D</sub>	T <sub>C</sub> = 25°C	400	W
T <sub>J</sub>		-55 ... +150	°C
T <sub>JM</sub>		150	°C
T <sub>stg</sub>		-55 ... +150	°C
T <sub>L</sub>	1.6mm (0.062in.) from Case for 10s	300	°C
T <sub>sold</sub>	Plastic Body for 10 seconds	260	°C
M <sub>d</sub>	Mounting Torque	1.13 / 10	Nm/lb.in.
Weight		6	g

Symbol	Test Conditions (T <sub>J</sub> = 25°C, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	500		V
V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	3.5		V
I <sub>GSS</sub>	V <sub>GS</sub> = ±30V, V <sub>DS</sub> = 0V			±100 nA
I <sub>DSS</sub>	V <sub>DS</sub> = V <sub>DSS</sub> , V <sub>GS</sub> = 0V T <sub>J</sub> = 125°C			50 μA 500 μA
R <sub>DS(on)</sub>	V <sub>GS</sub> = 20V, I <sub>D</sub> = 0.5 • I <sub>D25</sub> , Note 1			300 mΩ

### Features

- Designed for Linear Operation
- International Standard Package
- Avalanche Rated
- Molding Epoxy Meets UL94 V-0 Flammability Classification

### Advantages

- Easy to Mount
- Space Savings
- High Power Density

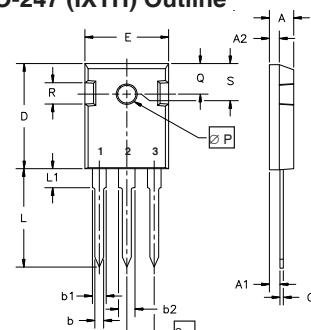
### Applications

- Programmable Loads
- Current Regulators
- DC-DC Converters
- Battery Chargers
- DC Choppers
- Temperature and Lighting Controls

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$V_{DS} = 20\text{V}$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1	3	7	11 S
$C_{iss}$		2500		pF
$C_{oss}$		400		pF
$C_{rss}$		100		pF
$t_{d(on)}$		35		ns
$t_r$		85		ns
$t_{d(off)}$	$V_{GS} = 15\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$ $R_G = 4.7\Omega$ (External)	110		ns
$t_f$		75		ns
$Q_{g(on)}$		160		nC
$Q_{gs}$	$V_{GS} = 20\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$	30		nC
$Q_{gd}$		50		nC
$R_{thJC}$			0.31	$^\circ\text{C}/\text{W}$
$R_{thCS}$		0.21		$^\circ\text{C}/\text{W}$

### Safe-Operating-Area Specification

Symbol	Test Conditions	Characteristic Values		
		Min.	Typ.	Max.
SOA	$V_{DS} = 400\text{V}$ , $I_D = 0.5\text{A}$ , $T_c = 60^\circ\text{C}$	200		W

**TO-247 (IXTH) Outline**

 Terminals: 1 - Gate  
3 - Source

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.7	5.3	.185	.209
A <sub>1</sub>	2.2	2.54	.087	.102
A <sub>2</sub>	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b <sub>1</sub>	1.65	2.13	.065	.084
b <sub>2</sub>	2.87	3.12	.113	.123
C	.4	.8	.016	.031
D	20.80	21.46	.819	.845
E	15.75	16.26	.610	.640
e	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L1		4.50		.177
ØP	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	242	BSC

### Source-Drain Diode

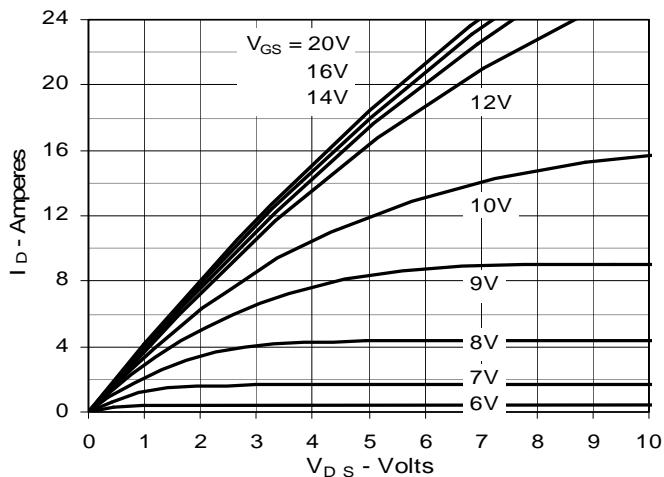
Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$I_s$	$V_{GS} = 0\text{V}$		24	A
$I_{SM}$	Repetitive, Pulse Width Limited by $T_{JM}$		96	A
$V_{SD}$	$I_F = I_S$ , $V_{GS} = 0\text{V}$ , Note 1		1.5	V
$t_{rr}$	$I_F = I_S$ , $-di/dt = 100\text{A}/\mu\text{s}$ $V_R = 100\text{V}$ , $V_{GS} = 0\text{V}$	500		ns

 Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

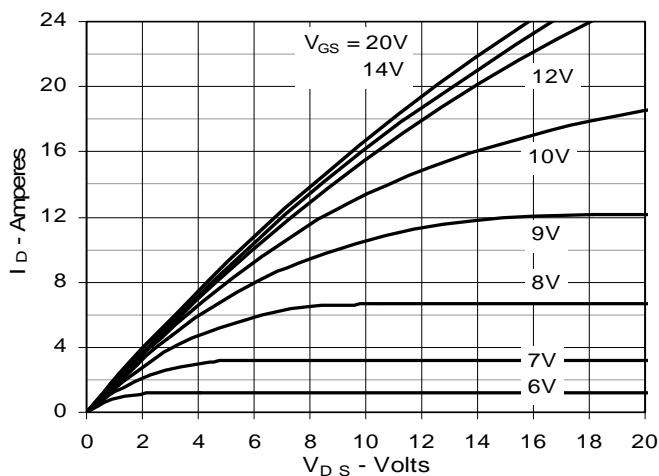
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585 7,005,734 B2 7,157,338B2 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,710,405 B2 6,759,692 7,063,975 B2 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463 6,771,478 B2 7,071,537

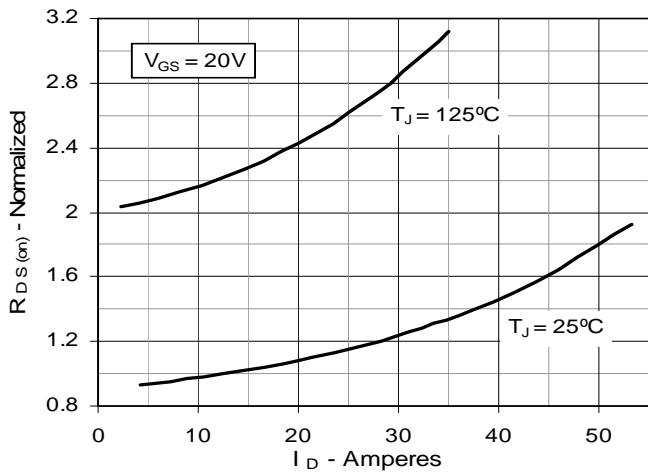
**Fig. 1. Output Characteristics  
@  $T_J = 25^\circ\text{C}$**



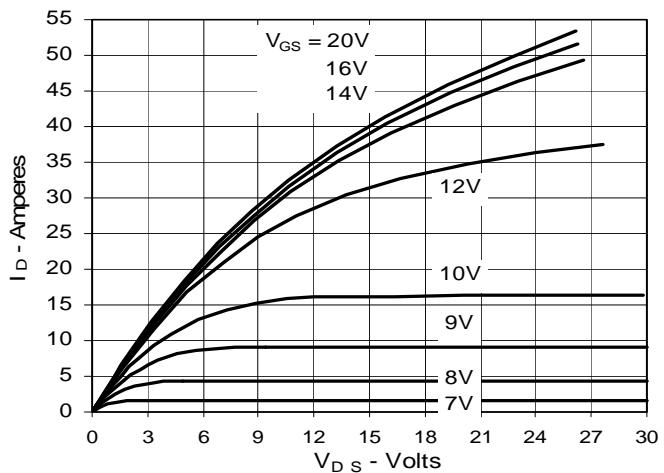
**Fig. 3. Output Characteristics  
@  $T_J = 125^\circ\text{C}$**



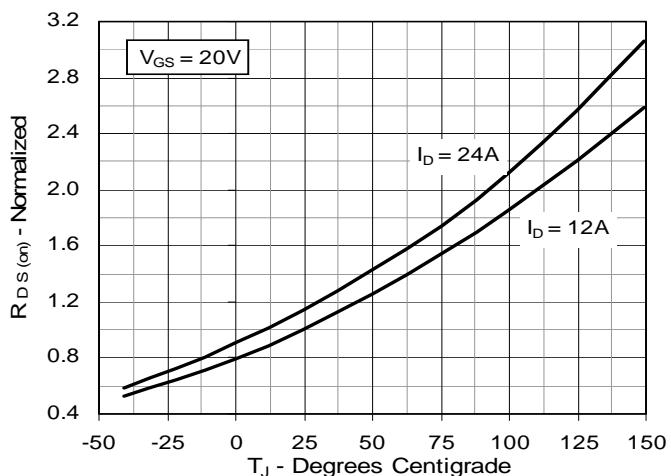
**Fig. 5.  $R_{DS(on)}$  Normalized to  
0.5  $I_{D25}$  Value vs.  $I_D$**



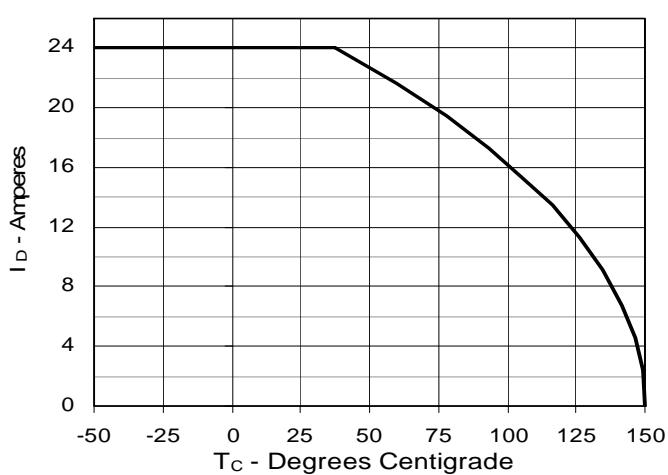
**Fig. 2. Extended Output Characteristics  
@  $T_J = 25^\circ\text{C}$**



**Fig. 4.  $R_{DS(on)}$  Normalized to 0.5  $I_{D25}$  Value  
vs. Junction Temperature**



**Fig. 6. Drain Current vs. Case Temperature**



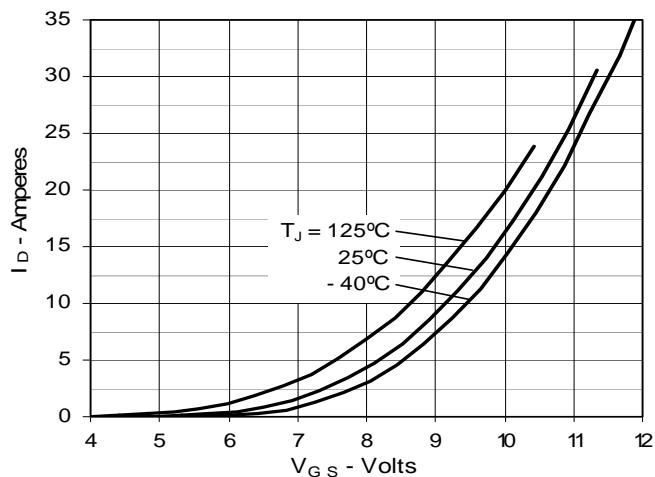
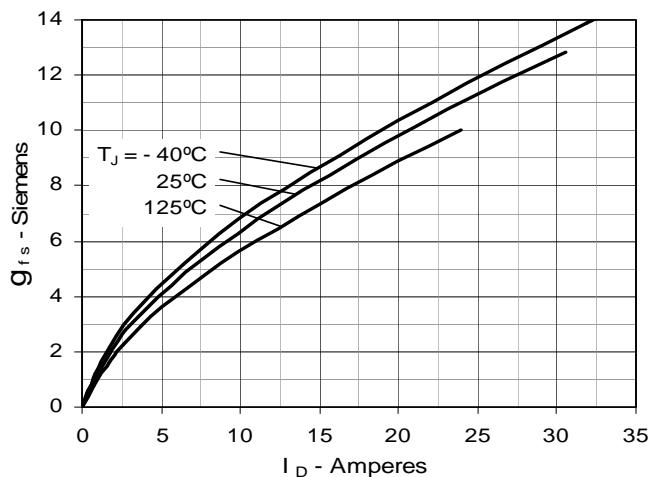
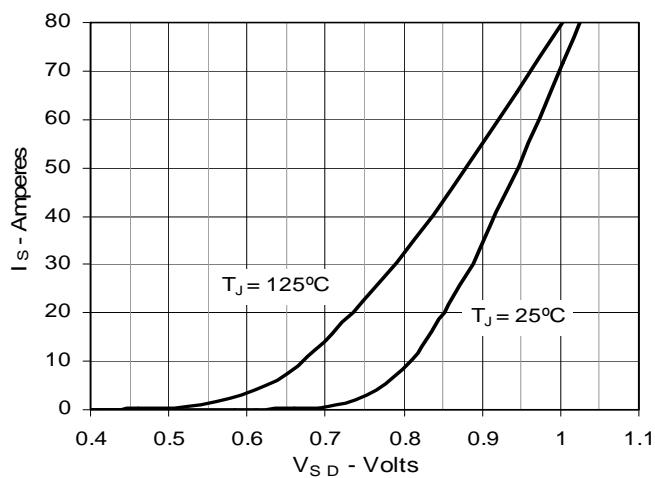
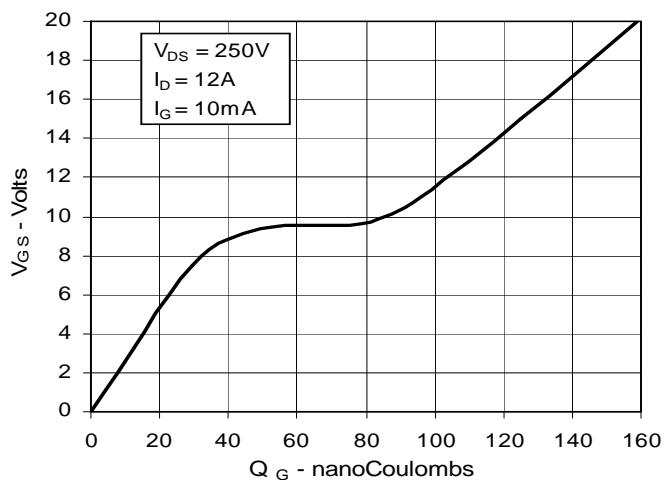
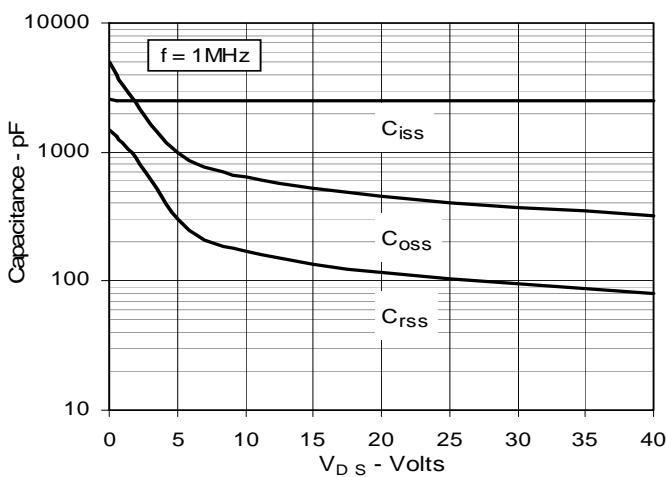
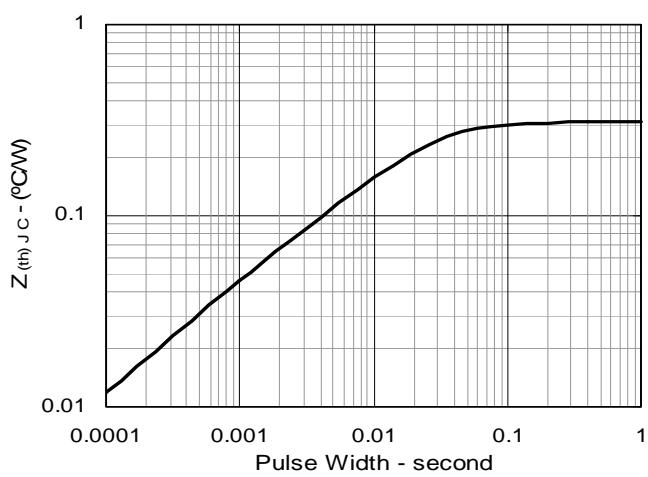
**Fig. 7. Input Admittance****Fig. 8. Transconductance****Fig. 9. Source Current vs. Source-To-Drain Voltage****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Maximum Transient Thermal Impedance**

Fig. 13. Forward-Bias Safe  
Operating Area @  $T_C = 25^\circ\text{C}$

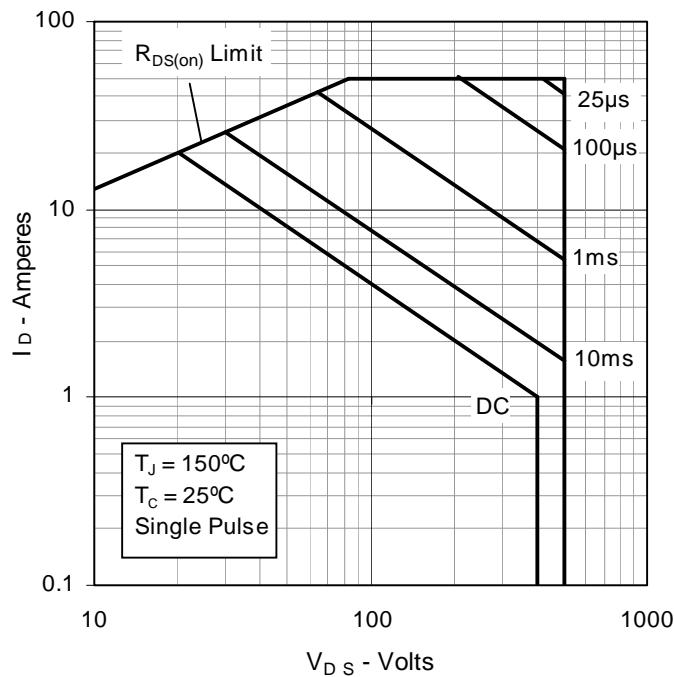
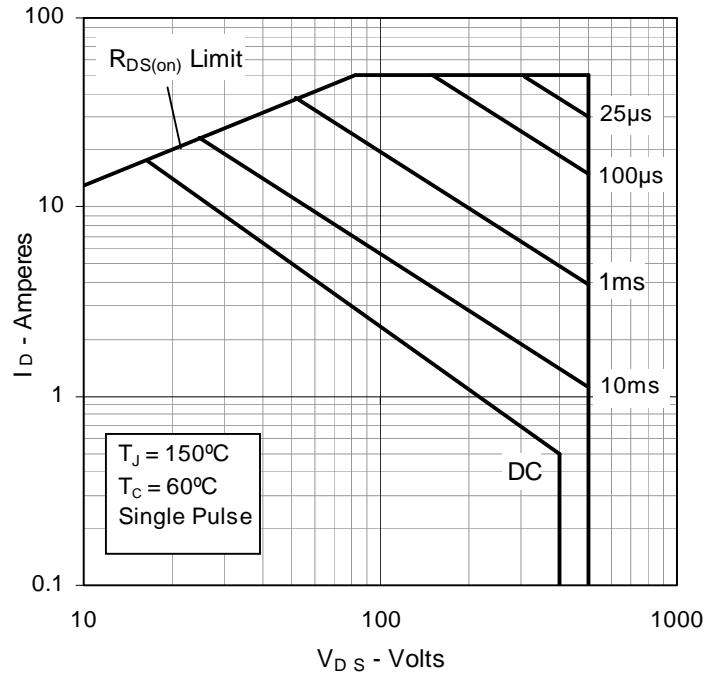


Fig. 14. Forward-Bias Safe  
Operating Area @  $T_C = 60^\circ\text{C}$



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